

# 50 MIPS, 32 kB Flash, 12-Bit ADC, 40-Pin Automotive MCU

## **Analog Peripherals**

### 12-Bit ADC, 5 V input signal; up to 32 external inputs

- ±1 LSB INL; guaranteed monotonic
- Programmable throughput up to 200 ksps
- Data-dependent windowed interrupt generator
- Programmable gain maximizes input signal span

### Built-in Temperature Sensor (±3 °C)

**Two Comparators** 

**Precision Internal Voltage Reference** 

**V<sub>DD</sub> Monitor/Brown-out Detector** 

# On-Chip Debug

- On-chip debug circuitry facilitates full speed, non-intrusive in-system debug (no emulator required)
- Provides breakpoints, single stepping, watch-points
- Inspect/modify memory, registers, and stack
- Superior performance to emulation systems using ICE-chips, target pods, and sockets

Temperature Range: -40 to +125 °C

Operating Voltage: 1.8 to 5.25 V

- Multiple power saving sleep and shutdown modes

**Development Kit: C8051F560DK** 

## High-Speed 8051 µC Core

- Pipelined instruction architecture; executes 70% of instructions in one or two system clocks
- Up to 50 MIPS throughput

### Memory

- 32 kB Flash; in-system programmable; flexible security features
- 2304 bytes data RAM (256 + 2 kB)

#### I IN 2.1

- Master or slave operation using dedicated hardware

# **Digital Peripherals**

- Up to 33 digital I/O; all are 5 V push-pull
- Hardware I<sup>2</sup>C, SPI<sup>™</sup>, and UART serial ports available concurrently
- Programmable 16-bit counter array with six capture/compare modules
- Four general-purpose 16-bit counter/timers
- External Memory Interface (EMIF)

### **Clock Sources**

- Internal programmable 0.5% oscillator: Up to 50 MHz
- External oscillator: Crystal, RC, C, or CMOS Clock

### **Ordering Part Numbers**

- C8051F570-IM, 40-Pin QFN (RoHS-compliant), 6 x 6 mm<sup>2</sup>

